

	U.S. Department of Commerce, Patent and Trademark	Atty. Docket No.	Application No.
	INFORMATION DISCLOSURE STATEMENT BY APPLICANT	SNDK.006USS	09/129,675
	(Use several sheets if necessary)	Applicant(s)	Conf. No.
	(Form PTO-1449)	Harari <i>et al.</i>	4949
		Filing Date	Art Group
		August 5, 1998	2824

U.S. Patent Documents

*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
AT	1	4,890,259	12/26/89	Simko	365	185.03

U.S. Published Patent Application Documents

*Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

Foreign Patent Documents

							Translation	
	Document	Date	Country	Class	Subclass		Yes	No

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

AT	2	Prior Art Cited by STMicro re U.S. Patent 5,172,338 – U.S. Patent and Application, 34 pages.
AT	3	Prior Art Cited by STMicro re U.S. Patent 5,172,338 – Foreign Patents/Applications; Publications; Data Sheets and Web Pages, 27 pages.
AT	4	Public Version of Complainant SanDisk Corporation's Reply to Respondents' Post-Hearing Brief, Investigation No. 337-TA-526, October 7, 2005, pp 81-128.
AT	5	Public Version of Complainant SanDisk Corporation's Post-Hearing Brief, Investigation No. 337-TA-526, October 7, 2005, pp. 99-134.

Examiner/Andrew Tran/

Date Considered 12/22/2006

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

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U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
AT	1	4,698,750	10/6/87	Wilkie et al.	365	185.04	
	2	5,222,046	6/22/93	Kreifels et al.	365	185.22	
	3	5,768,191	6/16/98	Choi et al.	365	185.22	
	4	6,118,703	9/12/00	Hamaguchi	365	185.22	
	5	6,496,446	12/17/02	Suzuki	365	238.5	
AT	6	4,989,179	1/29/91	Simko	365	185.03	

U.S. Published Patent Application Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
AT	7	JP2-10596	1/16/90	Japan	G11C	16/06		✓
	8	JP3-286497	12/17/91	Japan	G11C	16/06	Abstract	
	9	JP4-82090	3/16/92	Japan	G11C	16/06	Abstract	
	10	JP9-106689	4/22/97	Japan	G11C	16/06	Abstract	
AT	11	JP11-176185	7/2/99	Japan	G11C	17/18	Abstract	

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)		

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(Use several sheets if necessary)				Eliyahou Harari et al.		4949	
(Form PTO-1449)				Filing Date		Art Group	
				August 5, 1998		2824	
U.S. Patent Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
AT	1	4,752,871	6/21/1988	Sparks et al.	365	185.11	
AT	2	5,136,541	8/4/1992	Arakawa	365	185.23	
Foreign Patent Documents							
							Translation
		Document	Date	Country	Class	Subclass	Yes No
AT	3	JP S 59-121696	7/13/1984	Japan	G11C	17/00	X
AT	4	JP H62-6493	1/13/1987	Japan	G11C	17/00	X
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
AT	5	S. Mehrotra et al., "Serial 9Mb Flash EEPROM for Solid State Disk Applications," 1992 Symposium on VLSI Circuits Digest of Technical Papers, IEEE, pp. 24-25.					
AT	6	David A. Rich, "A Survey of Multivalued Memories," IEEE Transaction of Computers, Vol. C-35, No. 2, February, 1986, pp. 99-106.					
AT	7	Clinton Kuo et al., "An 80 ns 32K EEPROM Using the FETMOS Cell," IEEE Journal of Solid-State Circuits, Vol. SC-17, No. 5, October, 1982, pp. 821-827.					
AT	8	Electronic Industries Association, JEDEC Standard, "Configurations for Solid State Memories, JEDEC Standard No. 21-B (Revision of JESD21-A and JESD21-A-1), CS-0336, 337-TA-560, December, 1988, pp. i-36, 39-147.					
AT	9	"Expert Report of Dr. Richard Pashley Regarding the Invalidity of U.S. Patent No. 5,172,338 and U.S. Patent No. 5,991,517," United States International Trade Commission, Investigation No. 337-TA-560, September 7, 2006, pp. i-387.					
AT	10	"Rebuttal Expert Report of G.R. Mohan Rao, Ph.D. Regarding Validity and Enforceability of U.S. Patent Nos. 5,172,338 and 5,991,517," United States International Trade Commission, Investigation No. 337-TA-560, September 26, 2006, pp. i-245, Exhibit List, 6 pages.					
AT	11	"Addendum to the Rebuttal Expert Report of G.R. Mohan Rao, Ph.D. Regarding Validity and Enforceability of U.S. Patent Nos. 5,172,338 and 5,991,517," United States International Trade Commission, Investigation No. 337-TA-560, September 28, 2006, 5 pages.					
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